

High Voltage Transistor PNP Silicon PZTA96ST1G

Features

 These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	-450	Vdc
Collector-Base Voltage	V _{CBO}	-450	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current	Ic	-500	mAdc
Total Power Dissipation Up to T _A = 25°C (Note 1)	P _D	1.5	W
Storage Temperature Range	T _{stg}	-65 to +150	°C
Junction Temperature	TJ	150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Device mounted on a glass epoxy printed circuit board 1.575 in. x 1.575 in. x 0.059 in.; mounting pad for the collector lead min. 0.93 in².

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	83.3	°C

Device mounted on a glass epoxy printed circuit board 1.575 in. x 1.575 in. x 0.059 in.; mounting pad for the collector lead min. 0.93 in².

ELECTRICAL CHARACTERISTICS (Note 3)

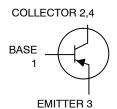
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				_
Collector–Emitter Breakdown Voltage (I _C = -1.0 mAdc, I _B = 0)	V _{(BR)CEO}	-450	-	Vdc
Collector–Emitter Breakdown Voltage (I _C = -100 μAdc, I _E = 0)	V _{(BR)CBO}	-450	-	Vdc
Emitter–Base Breakdown Voltage (I _E = -10 μAdc, I _C = 0)	V _{(BR)EBO}	-5.0	-	Vdc
Collector–Base Cutoff Current (V _{CB} = -400 Vdc, I _E = 0)	I _{CBO}	-	-0.1	μAdc
Emitter-Base Cutoff Current (V _{BE} = -4.0 Vdc, I _C = 0)	I _{EBO}	_	-0.1	μAdc

ON CHARACTERISTICS

DC Current Gain (Note 4) (I _C = -10 mAdc, V _{CE} = -10 Vdc)	h _{FE}	50	150	-
Saturation Voltages				Vdc
$(I_C = -20 \text{ mAdc}, I_B = -2.0 \text{ mAdc})$	V _{CE(sat)}	-	-0.6	
$(I_C = -20 \text{ mAdc}, I_B = -2.0 \text{ mAdc})$	V _{BE(sat)}	-	-1.0	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 3. $T_A = 25^{\circ}C$ unless otherwise noted.
- 4. Pulse Test: Pulse Width \leq 300 μ s; Duty Cycle = 2.0%.





SOT-223 (TO-261) CASE 318E STYLE 1

MARKING DIAGRAM



= Assembly Location

Y = Year

N = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
PZTA96ST1G	SOT-223 (Pb-Free)	1000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PZTA96ST1G

TYPICAL CHARACTERISTICS

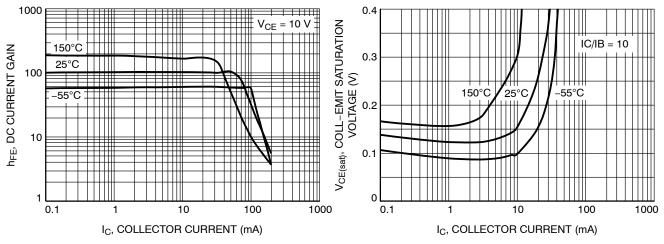


Figure 1. DC Current Gain

Figure 2. Collector-Emitter Saturation Voltage

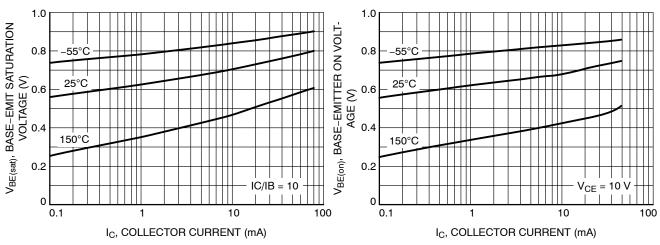
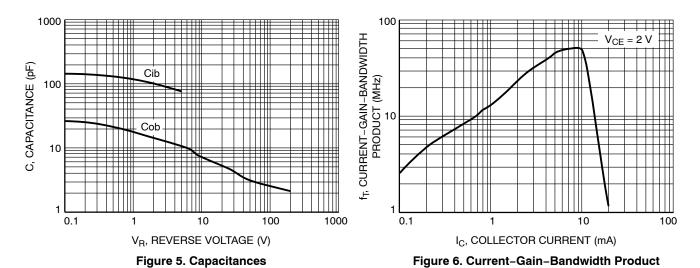


Figure 3. Base-Emitter Saturation Voltage

Figure 4. Base-Emitter "On" Voltage

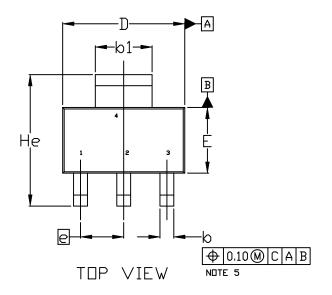


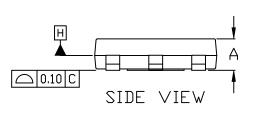


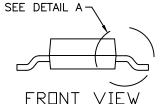


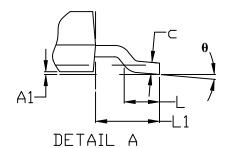
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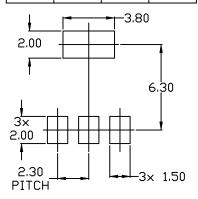




NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
 MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- 4. DATUMS A AND B ARE DETERMINED AT DATUM H.
- 5. AI IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
- 6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS 6 AND 61.

	MILLIMETERS		
DIM	MIN.	N□M.	MAX.
Α	1.50	1.63	1.75
A1	0.02	0.06	0.10
Ø	0.60	0.75	0.89
b1	2.90	3.06	3.20
U	0.24	0.29	0.35
D	6.30	6.50	6.70
E	3.30	3.50	3.70
е	2.30 BSC		
L	0.20		
L1	1.50	1.75	2.00
He	6.70	7.00	7.30
θ	0°		10°



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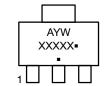
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STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE	STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 4: PIN 1. SOURCE 2. DRAIN 3. GATE 4. DRAIN	STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE
STYLE 6: PIN 1. RETURN 2. INPUT 3. OUTPUT 4. INPUT	STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE	STYLE 8: CANCELLED	STYLE 9: PIN 1. INPUT 2. GROUND 3. LOGIC 4. GROUND	STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE
STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2	STYLE 12: PIN 1. INPUT 2. OUTPUT 3. NC 4. OUTPUT	STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		

GENERIC MARKING DIAGRAM*



A = Assembly Location

Y = Year W = Work Week

XXXXX = Specific Device Code

= Pb-Free Package

(Note: Microdot may be in either location)
*This information is generic. Please refer to
device data sheet for actual part marking.
Pb-Free indicator, "G" or microdot "•", may
or may not be present. Some products may

not follow the Generic Marking.

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